

STG4260

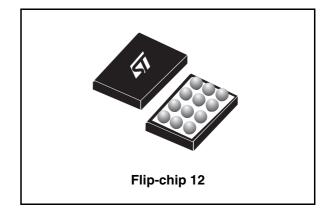
Low voltage 0.5 Ω dual SPDT switch with break-before-make feature and 15 kV ESD protection

Features

- Wide operating voltage range: V_{CC} (OPR) = 1.65 to 4.8 V
- Low power dissipation: $I_{CC} = 0.2 \,\mu\text{A} \,(\text{max.}) \,\text{at T}_{A} = 85 \,^{\circ}\text{C}$
- Low "ON" resistance:
 - R_{ON} = 0.75 Ω (T_A = 25 °C) at V_{CC} = 2.25 V
 - R_{ON} = 0.50 Ω (T_A = 25 $^{\circ}$ C) at V_{CC} = 3.0 V
 - R_{ON} = 0.40 Ω (T_A = 25 $^{\circ}$ C) at V_{CC} = 4.3 V
- Separate supply voltage for switch and control pin
- Latch-up performance exceeds 100 mA per JESD 78, Class II
- ESD performance tested on common pin (D pin):
 - 15 kV IEC-61000-4-2 ESD, contact discharge
 - 8 kV HBM JESD22 A114-B Class II
- ESD performance tested on S1 and S2 pin:
 - 8 kV IEC-61000-4-2 ESD, contact discharge
- ESD performance test on all other pins:
 - 4 kV HBM (JESD22 A114-B Class II)
 - 400 V machine model (JESD22 A115-A)
 - 1500 V charged-device model (JESD22 C101)

Applications

■ Mobile phones



Description

The STG4260 is a high-speed CMOS low voltage dual analog SPDT (single pole dual throw) switch or 2:1 multiplexer/demultiplexer switch fabricated in silicon gate C²MOS technology. It is designed to operate from 1.65 V to 4.8 V, making this device ideal for portable applications. It offers low ON-resistance (0.40 Ω typ.) at V_{CC} = 4.3 V. The SEL inputs are provided to control the switches.

The switch S1 is ON (connected to common port D) when the SEL input is held high and OFF (high impedance state exists between the two ports) when SEL is held low; the switch S2 is ON (it is connected to common Port D) when the SEL input is held low and OFF (high impedance state exists between the two ports) when SEL is held high.

Additional key features are fast switching speed, break-before-make delay time and ultra low power consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Table 1. Device summary

Order code	Package	Packing
STG4260BJR	Flip-chip 12	Tape and reel

Contents STG4260

Contents

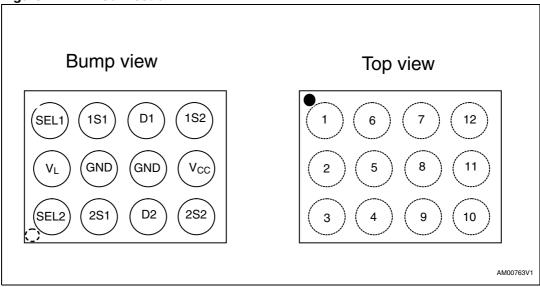
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STG4260 Pin settings

1 Pin settings

1.1 Pin connections

Figure 1. Pin connection



1.2 Pin description

Table 2. Pin assignment

Pin number	Symbol	Name and function		
1	SEL2	Selection control for switch 2		
2	V _L	Logic supply voltage		
3	SEL1	Selection control for switch 1		
4	1S1	Independent channel for switch 1		
5	GND	Ground (0 V)		
6	2S1	Independent channel for switch 2		
7	D2	Common channel for switch 2		
8	GND	Ground (0 V)		
9	D1	Common channel for switch 1		
10	1S2	Independent channel for switch 1		
11	V _{CC}	Positive supply voltage		
12	2S2	Independent channel for switch 2		

Logic diagram STG4260

2 Logic diagram

Figure 2. Functional diagram

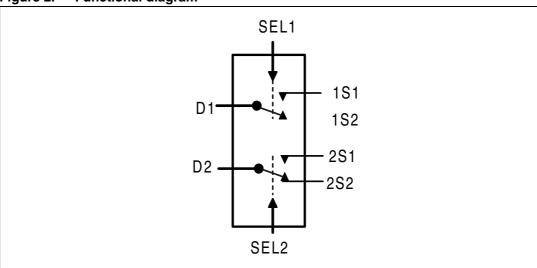


Figure 3. Circuit equivalent logic

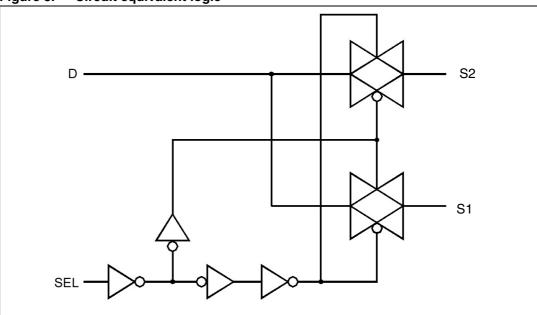


Table 3. Truth table

SEL	Switch S1	Switch S2	
Н	ON	OFF ⁽¹⁾	
L	OFF ⁽¹⁾	ON	

1. High impedance

STG4260 Maximum ratings

3 Maximum ratings

Stressing the device above the rating listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute maximum rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to 5.5	V
V _L	Logic supply voltage	-0.5 to 5.5	V
V _I	DC input voltage	-0.5 to V _{CC} + 0.5	V
V _{IC}	DC control input voltage	-0.5 to V _L + 5.5	V
V _O	DC output voltage	-0.5 to V _{CC} + 0.5	V
I _{IKC}	DC input diode current on control pin (V _{SEL} < 0 V)	- 50	mA
I _{IK}	DC input diode current (V _{SEL} < 0 V)	± 50	mA
I _{OK}	DC output diode current	± 20	mA
I _O	DC output current	± 300	mA
I _{OP}	DC output current peak (pulse at 1ms, 10% duty cycle)	± 500	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current	± 100	mA
P _D	Power dissipation at T _A = 70°C ⁽¹⁾	500	mW
T _{stg}	Storage temperature	-65 to 150	°C
T_L	Lead temperature (10 sec)	260	°C

^{1.} Derate above 70 °C by 18.5 mW/C

Table 5. Recommended operating conditions

Symbol	Parameter	•	Value	Unit	
V _{CC}	Supply voltage		1.65 to 4.8	V	
V_{L}	Logic supply voltage ⁽¹⁾		1.65 to V _{CC}	V	
V _I	Input voltage		0 to V _{CC}	V	
V _{IC}	Control input voltage		0 to V _L	V	
V _O	Output voltage		0 to V _{CC}	V	
T _{op}	Operating temperature		-40 to 85	°C	
dt/dv	Input rise and fall time control	$V_L = 1.65 \text{ to } 2.7 \text{ V}$	0 to 20	ns/V	
ui/uv	input	V _L = 3.0 to 4.8 V	0 to 10	115/ V	

^{1.} V_I pin should not be left floating.

Electrical characteristics STG4260

4 Electrical characteristics

Table 6. DC specifications

							Value			
Symbol	Parameter	V _{CC} V _L Test (V) (V)		Test condition	T	_A = 25 °	С	-40 to	85 °C	Unit
		(•)	(1)		Min	Тур	Max	Min	Max	
			1.65 – 1.95		1.25	_	_	1.25	-	
V	High level	1.65 – 4.3	2.3 – 2.7		1.75	_	_	1.75	-	v
V _{IH}	input voltage	1.05 – 4.5	3.0 – 3.6		2.34	_	_	2.34	_	
			4.3		2.80	_	_	2.80	-	
			1.65 – 1.95		_	_	0.6	_	0.6	
\ \v	Low level	1.65 – 4.3	2.3 – 2.7		_	_	0.8	_	0.8	v
V _{IL}	input voltage	1.05 – 4.5	3.0 – 3.6		_	_	1.05	_	1.05	
			4.3		_	_	1.5	_	1.5	
		1.8			-	1.5	2.5	_	3.7	
		2.25		$V_S = 0 \text{ V to}$ V_{CC} $I_S = 100 \text{ mA}$	ı	0.75	1.0	ı	1.3	Ω
R _{ON}	ON resistance	3	1.65 – 4.3		ı	0.50	0.65	1	8.0	
		3.7			-	0.45	0.55	-	0.7	
		4.3			_	0.40	0.50	_	0.65	
		1.8			_	40	_	_	_	
	ON resistance	2.25		$V_S = 0 V to$	-	20	_	_	-	
ΔR_{ON}	match between	3	1.65 – 4.3	$V_S = 0 \text{ V to}$ V_{CC} $I_S = 100 \text{ mA}$	_	10	_	_	_	mΩ
	channels ⁽¹⁾	3.7			ı	10	1	1	ı	
		4.3			-	10	-	-	-	
		1.8			ı	1000	1700	1	2000	
		2.25		$V_S = 0 V to$	ı	300	430	1	550	
R _{FLAT}	ON resistance flatness ⁽²⁾	3	1.65 – 4.3	V _{CC}	ı	170	220	ı	270	mΩ
		3.7		I _S = 100 mA	-	160	210	-	270	
		4.3			1	160	210	1	270	
l _{OFF}	Sn OFF state leakage current	4.3	4.3	$V_S = 0.3 \text{ to } 4.0$ $V_D = 0.3 \text{ to } 4.0$	-30	-	30	-300	300	nA
I _{ON}	Sn ON state leakage current	4.3	4.3	$V_S = 0.3 \text{ to } 4.0$ $V_D = \text{open}$	-30	_	30	-300	300	nA
I _D	D ON state leakage current	4.3	4.3	$V_S = \text{open}$ $V_D = 0.3 \text{ to } 4.0$	-30	_	30	-300	300	nA

Table 6. DC specifications (continued)

					Value					
Symbol	Parameter	V _{CC} (V)	V _L (V)	Test condition	T,	_A = 25 °	С	-40 to	85 °C	Unit
		, ,	, ,		Min	Тур	Max	Min	Max	
I _{CC}	Quiescent supply current	1.65 – 4.3	1.65 – 4.3	V _{SEL} = V _{CC} or GND	-0.05	_	0.05	-0.2	0.2	μА
I _{SEL}	SEL leakage current	1.65 – 4.3	1.65 – 4.3	V _{SEL} = 4.3V or GND	-0.2	-	0.2	-2	2	μА

^{1.} $\Delta R_{ON} = R_{ON(Max)} - R_{ON(Min)}$

Table 7. AC electrical characteristics ($C_L = 35 \text{ pF}, R_L = 50 \Omega, t_r = t_f \le 5 \text{ ns}$)

		v _{cc}			Value					Unit
Symbol	Symbol Parameter		V _L (V)	Test conditions	T _A = 25°C			-40 to 85°C		
		(V)	,		Min	Тур	Max	Min	Max	
		1.65-1.95			_	0.18	_	-	_	
t _{PLH} , t _{PHL}	Propagation	2.3 – 2.7	1.65 –		ı	0.14	ı	ı	_	ns
PLH, PHL	delay	3.0 - 3.3	4.3		ı	0.12	ı	ı	_	113
		3.6 – 4.3			1	0.12	1	ı	_	
		1.65 – 1.95		1.65 - $R_L = 50 \Omega$ $C_L = 30 pF$	-	70	123	-	160	
t _{ON}	TURN-ON time	2.3 – 2.7	1.65 – 4.3		_	48	62	_	80	ns
		3 – 3.6			ı	33	43	ı	56	
		4.3				_	29	38	-	49
		1.65 – 1.95		$V_S = V_{CC}$	1	36	45	I	60	
t _{OFF}	TURN-OFF time	2.3 – 2.7	1.65 –	$V_S = V_{CC}$ $R_L = 50 \Omega$ $C_L = 30 pF$	ı	35	47	ı	62	ns
	une	3 – 3.6	4.5	$C_L = 30 pF$	ı	30	40	ı	51	- -
		4.3			_	29	38	-	50	
		1.65 – 1.95		C ₁ = 35 pF	10	42	_	-	-	
Break-before- t _D make time		2.3 – 2.7	1.65 – 4.3	$\begin{array}{c} 1.65 - \\ 4.3 \end{array} \begin{array}{c} C_{L} = 35 \text{ pF} \\ R_{L} = 50 \Omega \\ V_{S} = V_{CC}/2 \end{array}$	10	22	_	-	_	ns
	delay	3 – 3.6			5	15	_	-	_	
		4.3			5	12	_	-	_	

^{2.} Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Electrical characteristics STG4260

Table 7. AC electrical characteristics ($C_L = 35 \text{ pF}, R_L = 50 \Omega, t_r = t_f \le 5 \text{ ns}$) (continued) (continued)

							Value																													
Symbol	Parameter	V _{CC} (V)	(V)	Test conditions	٦	Γ _A = 25°C		-40 to 85°C		Unit																										
		,	,		Min	Тур	Max	Min	Max	-																										
		1.65 – 1.95			_	83	-	-	-																											
Q	Charge injection	2.3 – 2.7	1.65-4.3	$C_L = 1nF$ $V_{GEN} = 0 V$	-	98	ı	ı	_	рС																										
	Injection	3.0 – 3.3		V _{GEN} = 0 V	-	114	_	-	_																											
		3.6 – 4.3			_	140	_	_	_																											
				$V_S = 1V_{RMS}$ f = 100 kHz	_	77	_	_	-																											
OIRR	Off isolation ⁽¹⁾	1.65 – 4.3 4.3	$V_S = 1V_{RMS}$ f = 1 MHz	_	67	_	-	-	dB																											
				$V_S = 1V_{RMS}$ f = 5 MHz	_	50	_	-	-																											
				$V_S = 1V_{RMS}$ f = 100 kHz	_	80	_	_	-																											
Xtalk	Crosstalk	1.65 – 4.3		4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	4.3	43	4:3	4 3	4.3	4 3	4.3	4.3	4.3	$V_S = 1V_{RMS}$ f = 1 MHz	_	67	_	_	-
				$V_S = 1V_{RMS}$ f = 5 MHz	_	50	_	-	-																											
THD	Total harmonic distortion	2.3 – 4.3	4.3	$R_L = 600 \Omega$ $C_L = 50 \text{ pF}$ $V_S = V_{CC} V_{PP}$ $f = 600 \text{ Hz to}$ 20 kHz	-	0.01	-	-	_	%																										
BW	-3dB bandwidth (switch ON)	1.65 – 4.3	4.3	R _L = 50 Ω	-	50	_	_	_	MHz																										

^{1.} OFF-isolation = 20 \log_{10} (VD/VS), V_D = output, V_S = input to off switch

Table 8. Capacitive characteristics

							Value			
Symbol	Parameter	V _{CC} (V)	V _L (V)	Test condition	Т	A = 25 °	С	-40 to	85 °C	Unit
			,		Min	Тур	Max	Min	Max	
C _{SEL}	Control pin input capacitance	1.8 – 4.3	1.8 – 4.3	V _L = V _{CC}	-	30	-	-	-	pf
C _{SN}	Sn port capacitance	1.8 – 4.3	1.8 – 4.3	$V_L = V_{CC}$	-	94	-	-	_	pf
C _D	D port capacitance when the switch is enabled	1.8 - 4.3	1.8 – 4.3	V _L = V _{CC}	ı	227	-	-	-	pf

Test circuits STG4260

5 Test circuits

Figure 4. ON resistance

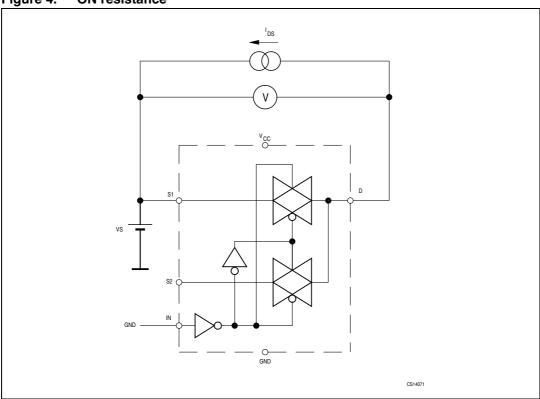
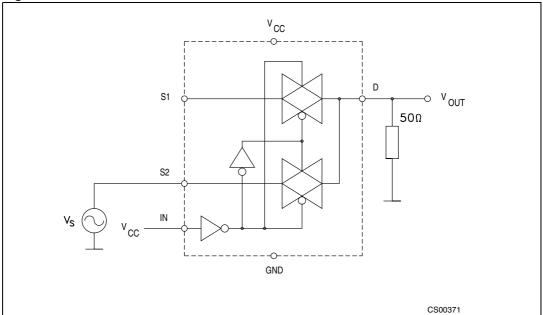


Figure 5. Bandwidth



STG4260 Test circuits

Figure 6. OFF leakage

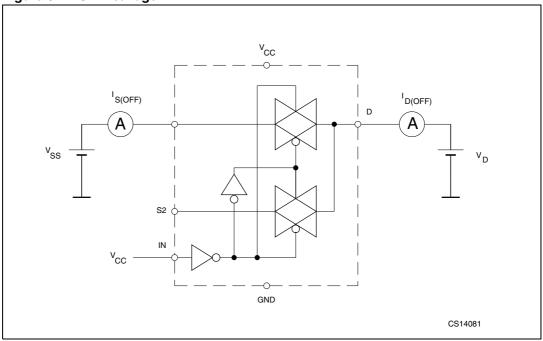
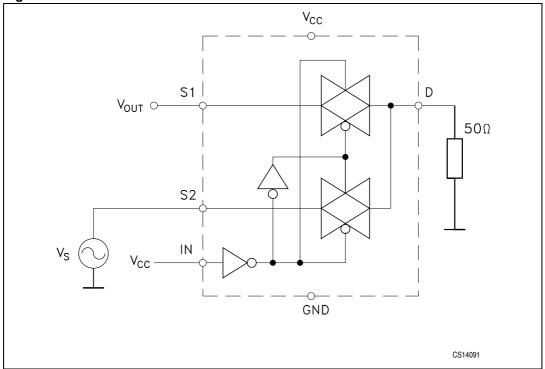


Figure 7. Channel-to-channel crosstalk



Test circuits STG4260

Figure 8. OFF isolation

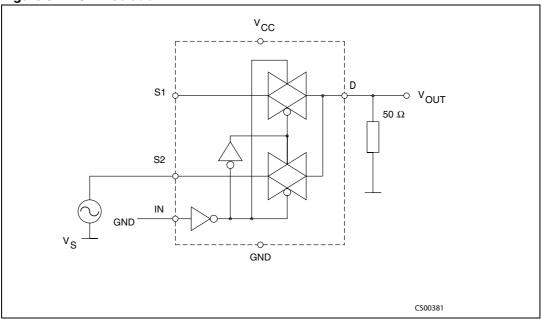
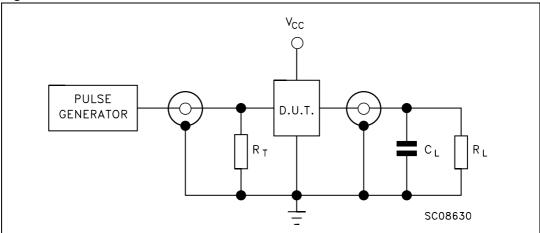


Figure 9. Test circuit



- 1. $C_L = 5/35$ pF or equivalent: (includes jig capacitance)
- 2. $R_L = 50 \Omega$ or equivalent
- 3. $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

STG4260 Test circuits

Figure 10. Break-before-make time delay

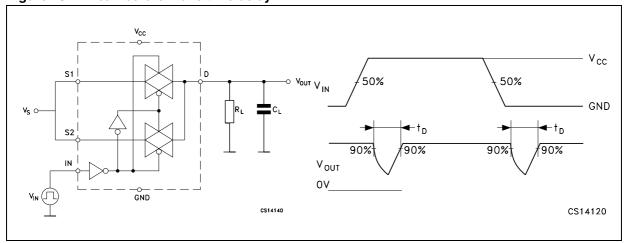


Figure 11. Switching time and charge injection

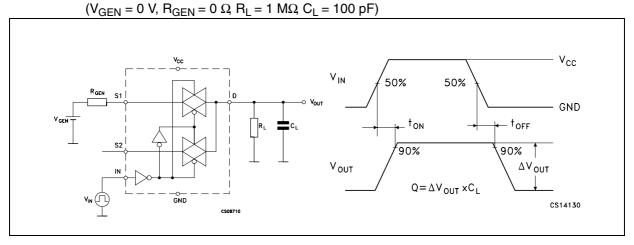
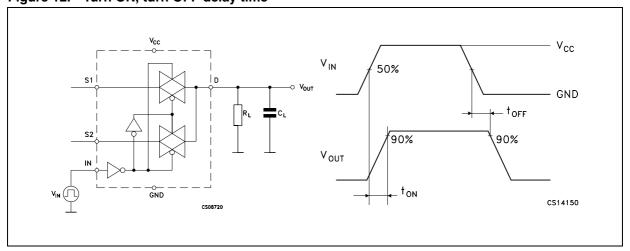


Figure 12. Turn ON, turn OFF delay time



6 Package mechanical data

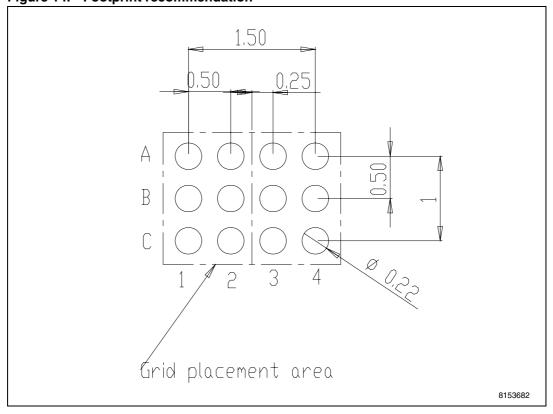
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 13. Package outline for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch TOP VIEW \forall △ ccc C \mathbb{C} В see note 1 BOTTOM VIEW 8153682

Table 9. Mechanical data for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch

Cumbal		Millimeters								
Symbol	Min	Тур	Max							
A	0.535	0.58	0.625							
A1	0.18	0.205	0.23							
A2	0.355	0.375	0.395							
b	0.215	0.255	0.295							
D	1.85	1.9	1.95							
D1	_	1.5	-							
е	0.45	0.5	0.55							
E	1.35	1.4	1.45							
E1	_	1	-							
SD	-	0.25	-							
f	0.19	0.2	0.21							
ccc	_	0.08	-							

Figure 14. Footprint recommendation



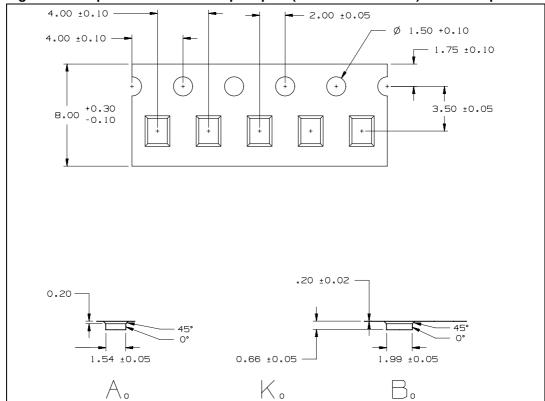
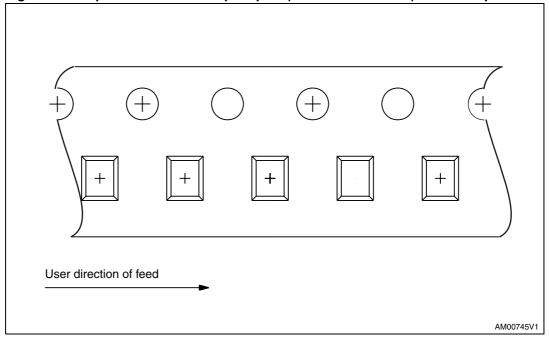


Figure 15. Tape information for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch





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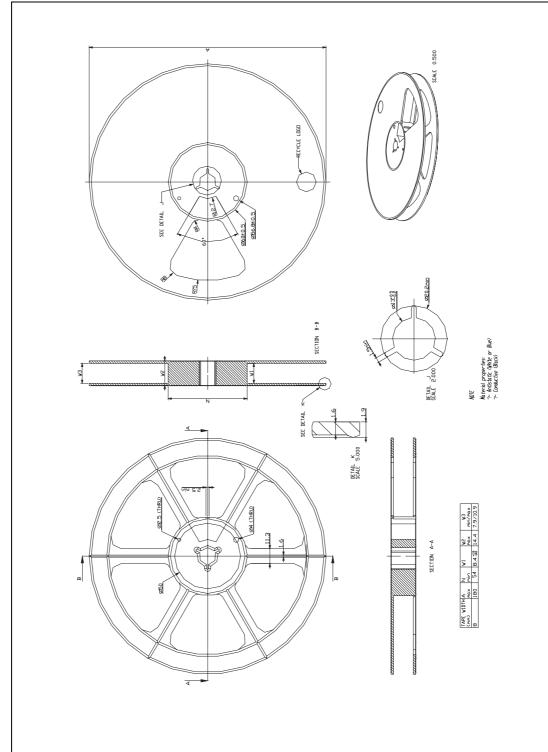


Figure 17. Reel information for Flip-chip 12 (1.9 x 1.4 x 0.58 mm) - 0.50 mm pitch

Revision history STG4260

7 Revision history

Table 10. Document revision history

Date	Revision	Changes
19-Nov-2008	1	Initial release.
20-Apr-2009	2	Document status promoted from preliminary data to datasheet. Modified: <i>Table 6: DC specifications on page 6</i> and <i>Section 6</i> .

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